

**74AC541**

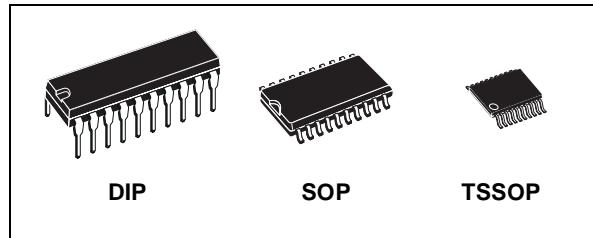
## OCTAL BUS BUFFER WITH 3 STATE OUTPUTS (NON INVERTED)

- HIGH SPEED:  $t_{PD} = 4\text{ns}$  (TYP.) at  $V_{CC} = 5\text{V}$
- LOW POWER DISSIPATION:  
 $I_{CC} = 4\mu\text{A}$ (MAX.) at  $T_A=25^\circ\text{C}$
- HIGH NOISE IMMUNITY:  
 $V_{NIH} = V_{NIL} = 28\%$   $V_{CC}$  (MIN.)
- 50 $\Omega$  TRANSMISSION LINE DRIVING CAPABILITY
- SYMMETRICAL OUTPUT IMPEDANCE:  
 $|I_{OHI}| = I_{OL} = 24\text{mA}$  (MIN)
- BALANCED PROPAGATION DELAYS:  
 $t_{PLH} \approx t_{PHL}$
- OPERATING VOLTAGE RANGE:  
 $V_{CC}$  (OPR) = 2V to 6V
- PIN AND FUNCTION COMPATIBLE WITH 74 SERIES 541
- IMPROVED LATCH-UP IMMUNITY

### DESCRIPTION

The 74AC541 is an advanced high-speed CMOS OCTAL BUS BUFFER (3-STATE) fabricated with sub-micron silicon gate and double-layer metal wiring C<sup>2</sup>MOS technology.

The 3 STATE control gate operates as two inputs AND such that if either G1 and G2 are high, all eight outputs are in the high impedance state.

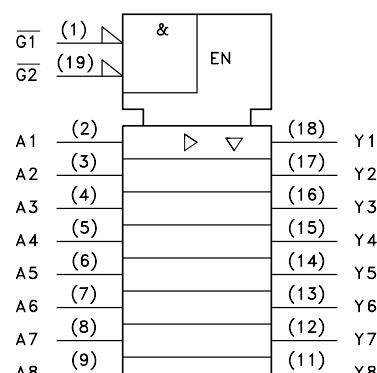
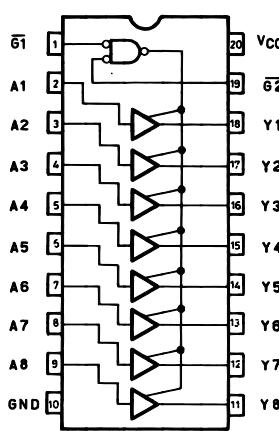


### ORDER CODES

PACKAGE	TUBE	T & R
DIP	74AC541B	
SOP	74AC541M	74AC541MTR
TSSOP		74AC541TTR

In order to enhance PC board layout, the 74AC541 offers a pinout having inputs and outputs on opposite sides of the package. All inputs and outputs are equipped with protection circuits against static discharge, giving them 2KV ESD immunity and transient excess voltage.

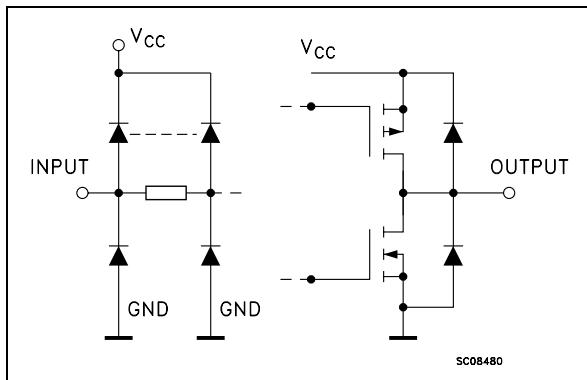
### PIN CONNECTION AND IEC LOGIC SYMBOLS



LC12880

# 74AC541

## INPUT AND OUTPUT EQUIVALENT CIRCUIT



## PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
1, 19	G <sub>1</sub> , G <sub>2</sub>	Output Enable Inputs
2, 3, 4, 5, 6, 7, 8, 9	A <sub>1</sub> to A <sub>8</sub>	Data Inputs
18, 17, 16, 15, 14, 13, 12, 11	Y <sub>1</sub> to Y <sub>8</sub>	Data Outputs
10	GND	Ground (0V)
20	V <sub>CC</sub>	Positive Supply Voltage

## TRUTH TABLE

INPUTS			OUTPUT
$\overline{G_1}$	$\overline{G_2}$	$A_n$	$Y_n$
H	X	X	Z
X	H	X	Z
L	L	H	H
L	L	L	L

X : Don't Care

Z : High Impedance

## ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply Voltage	-0.5 to +7	V
V <sub>I</sub>	DC Input Voltage	-0.5 to V <sub>CC</sub> + 0.5	V
V <sub>O</sub>	DC Output Voltage	-0.5 to V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	DC Input Diode Current	$\pm 20$	mA
I <sub>OK</sub>	DC Output Diode Current	$\pm 20$	mA
I <sub>O</sub>	DC Output Current	$\pm 50$	mA
I <sub>CC</sub> or I <sub>GND</sub>	DC V <sub>CC</sub> or Ground Current	$\pm 400$	mA
T <sub>stg</sub>	Storage Temperature	-65 to +150	°C
T <sub>L</sub>	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply Voltage	2 to 6	V
V <sub>I</sub>	Input Voltage	0 to V <sub>CC</sub>	V
V <sub>O</sub>	Output Voltage	0 to V <sub>CC</sub>	V
T <sub>op</sub>	Operating Temperature	-55 to 125	°C
dt/dv	Input Rise and Fall Time V <sub>CC</sub> = 3.0, 4.5 or 5.5V (note 1)	8	ns/V

1) V<sub>IN</sub> from 30% to 70% of V<sub>CC</sub>

## DC SPECIFICATIONS

Symbol	Parameter	Test Condition		Value						Unit	
		V <sub>CC</sub> (V)		T <sub>A</sub> = 25°C			-40 to 85°C		-55 to 125°C		
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
V <sub>IH</sub>	High Level Input Voltage	3.0	V <sub>O</sub> = 0.1 V or V <sub>CC</sub> -0.1V	2.1	1.5		2.1		2.1		V
		4.5		3.15	2.25		3.15		3.15		
		5.5		3.85	2.75		3.85		3.85		
V <sub>IL</sub>	Low Level Input Voltage	3.0	V <sub>O</sub> = 0.1 V or V <sub>CC</sub> -0.1V		1.5	0.9		0.9		0.9	V
		4.5			2.25	1.35		1.35		1.35	
		5.5			2.75	1.65		1.65		1.65	
V <sub>OH</sub>	High Level Output Voltage	3.0	I <sub>O</sub> =-50 μA	2.9	2.99		2.9		2.9		V
		4.5	I <sub>O</sub> =-50 μA	4.4	4.49		4.4		4.4		
		5.5	I <sub>O</sub> =-50 μA	5.4	5.49		5.4		5.4		
		3.0	I <sub>O</sub> =-12 mA	2.56			2.46		2.4		
		4.5	I <sub>O</sub> =-24 mA	3.86			3.76		3.7		
		5.5	I <sub>O</sub> =-24 mA	4.86			4.76		4.7		
V <sub>OL</sub>	Low Level Output Voltage	3.0	I <sub>O</sub> =50 μA		0.002	0.1		0.1		0.1	V
		4.5	I <sub>O</sub> =50 μA		0.001	0.1		0.1		0.1	
		5.5	I <sub>O</sub> =50 μA		0.001	0.1		0.1		0.1	
		3.0	I <sub>O</sub> =12 mA			0.36		0.44		0.5	
		4.5	I <sub>O</sub> =24 mA			0.36		0.44		0.5	
		5.5	I <sub>O</sub> =24 mA			0.36		0.44		0.5	
I <sub>I</sub>	Input Leakage Current	5.5	V <sub>I</sub> = V <sub>CC</sub> or GND			± 0.1		± 1		± 1	μA
I <sub>OZ</sub>	High Impedance Output Leakege Current	5.5	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>O</sub> = V <sub>CC</sub> or GND			± 0.3		± 2.5		± 5	μA
I <sub>CC</sub>	Quiescent Supply Current	5.5	V <sub>I</sub> = V <sub>CC</sub> or GND			4		40		80	μA
I <sub>OLD</sub>	Dynamic Output Current (note 1, 2)	5.5	V <sub>OLD</sub> = 1.65 V max					75		50	mA
			V <sub>OHD</sub> = 3.85 V min					-75		-50	mA

1) Maximum test duration 2ms, one output loaded at time

2) Incident wave switching is guaranteed on transmission lines with impedances as low as 50Ω

# 74AC541

## AC ELECTRICAL CHARACTERISTICS ( $C_L = 50 \text{ pF}$ , $R_L = 500 \Omega$ , Input $t_r = t_f = 3\text{ns}$ )

Symbol	Parameter	Test Condition		Value						Unit	
		$V_{CC}$ (V)		$T_A = 25^\circ\text{C}$			$-40 \text{ to } 85^\circ\text{C}$		$-55 \text{ to } 125^\circ\text{C}$		
				Min.	Typ.	Max.	Min.	Max.	Min.		
$t_{PLH}, t_{PHL}$	Propagation Delay Time	3.3 <sup>(*)</sup>		1.5	5.0	8.0	1.5	9.0	1.5	9.0	ns
		5.0 <sup>(**)</sup>		1.5	4.0	6.5	1.5	7.0	1.5	7.0	
$t_{PZL}, t_{PZH}$	Output Enable Time	3.3 <sup>(*)</sup>		1.5	7.0	10.5	1.5	11.5	1.5	11.5	ns
		5.0 <sup>(**)</sup>		1.5	5.0	8.0	1.5	8.5	1.5	8.5	
$t_{PLZ}, t_{PHZ}$	Output Disable Time	3.3 <sup>(*)</sup>		1.5	7.0	10.5	1.5	11.5	1.5	11.5	ns
		5.0 <sup>(**)</sup>		1.5	5.0	9.0	1.5	9.5	1.5	9.5	

(\*) Voltage range is  $3.3\text{V} \pm 0.3\text{V}$

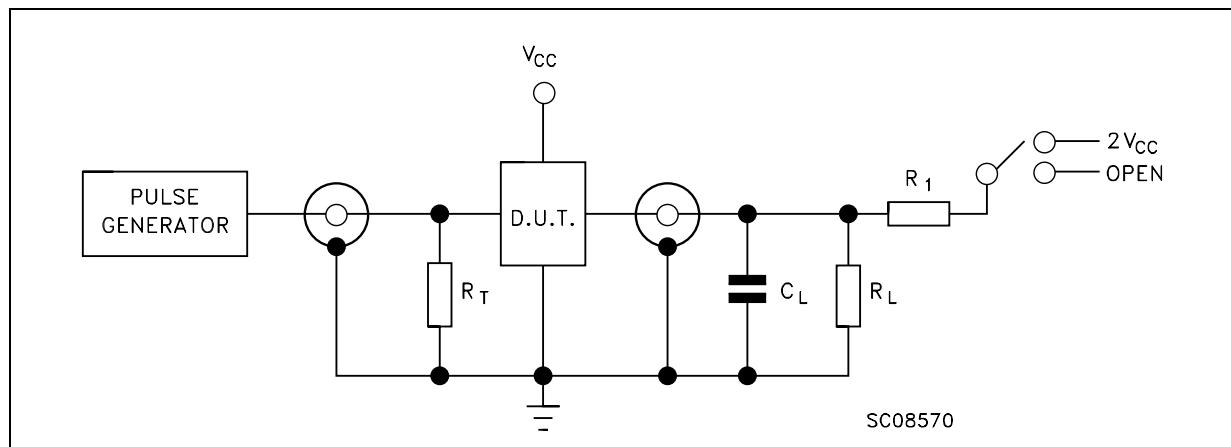
(\*\*) Voltage range is  $5.0\text{V} \pm 0.5\text{V}$

## CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Test Condition		Value						Unit	
		$V_{CC}$ (V)		$T_A = 25^\circ\text{C}$			$-40 \text{ to } 85^\circ\text{C}$		$-55 \text{ to } 125^\circ\text{C}$		
				Min.	Typ.	Max.	Min.	Max.	Min.		
$C_{IN}$	Input Capacitance	5.0			5					pF	
$C_{OUT}$	Output Capacitance	5.0			11					pF	
$C_{PD}$	Power Dissipation Capacitance (note 1)	5.0	$f_{IN} = 10\text{MHz}$		30					pF	

1)  $C_{PD}$  is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation.  $I_{CC(\text{opr})} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$  (per circuit)

## TEST CIRCUIT

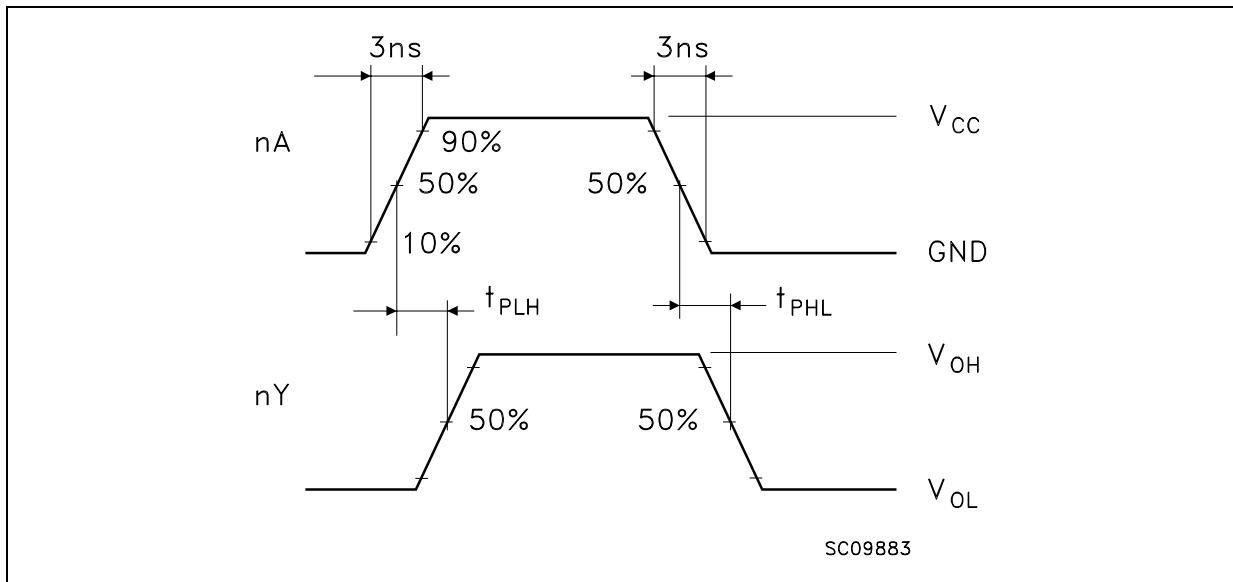
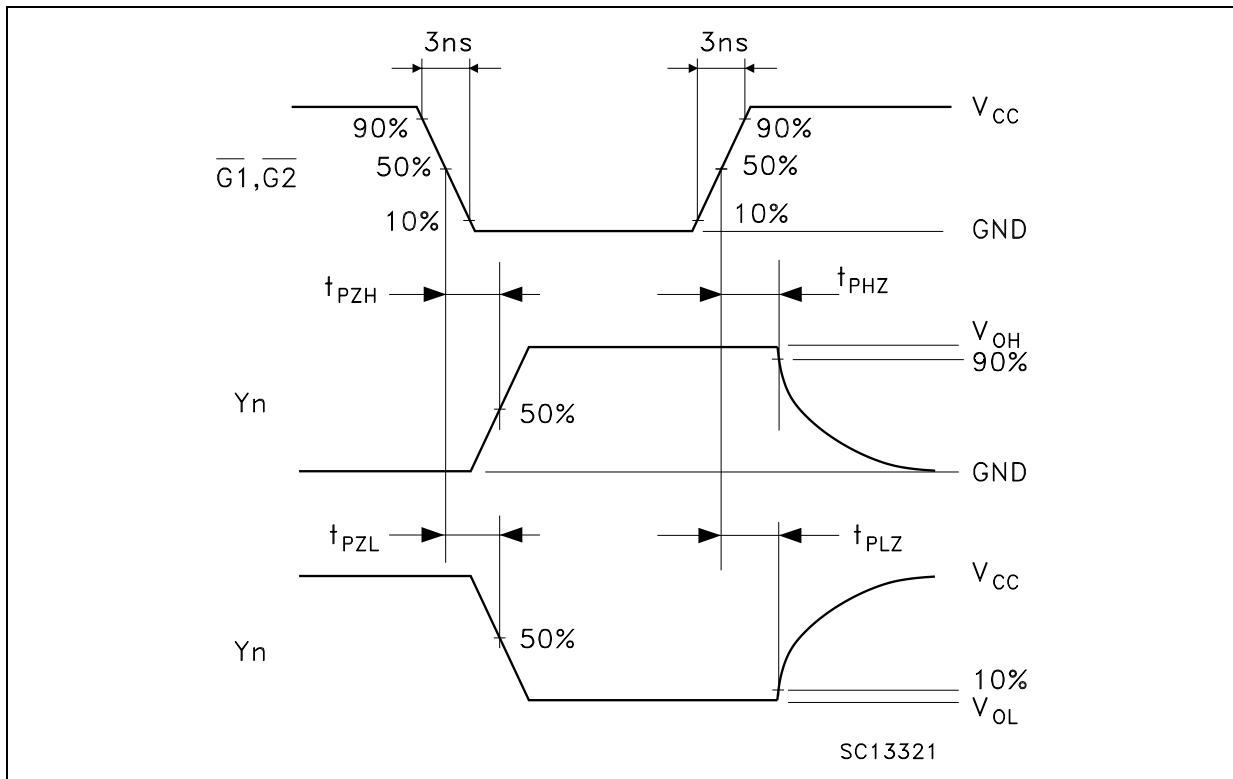


TEST	SWITCH
$t_{PLH}, t_{PHL}$	Open
$t_{PZL}, t_{PLZ}$	$2V_{CC}$
$t_{PZH}, t_{PHZ}$	Open

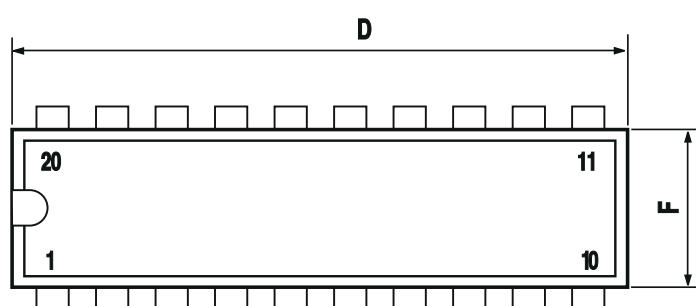
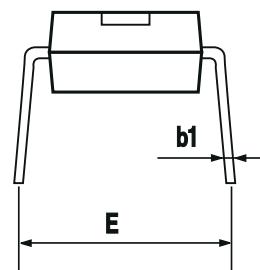
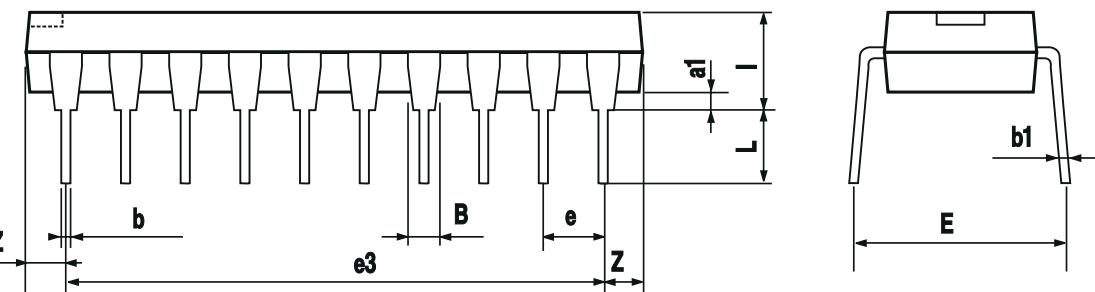
$C_L = 50\text{pF}$  or equivalent (includes jig and probe capacitance)

$R_L = R_1 = 500\Omega$  or equivalent

$R_T = Z_{OUT}$  of pulse generator (typically  $50\Omega$ )

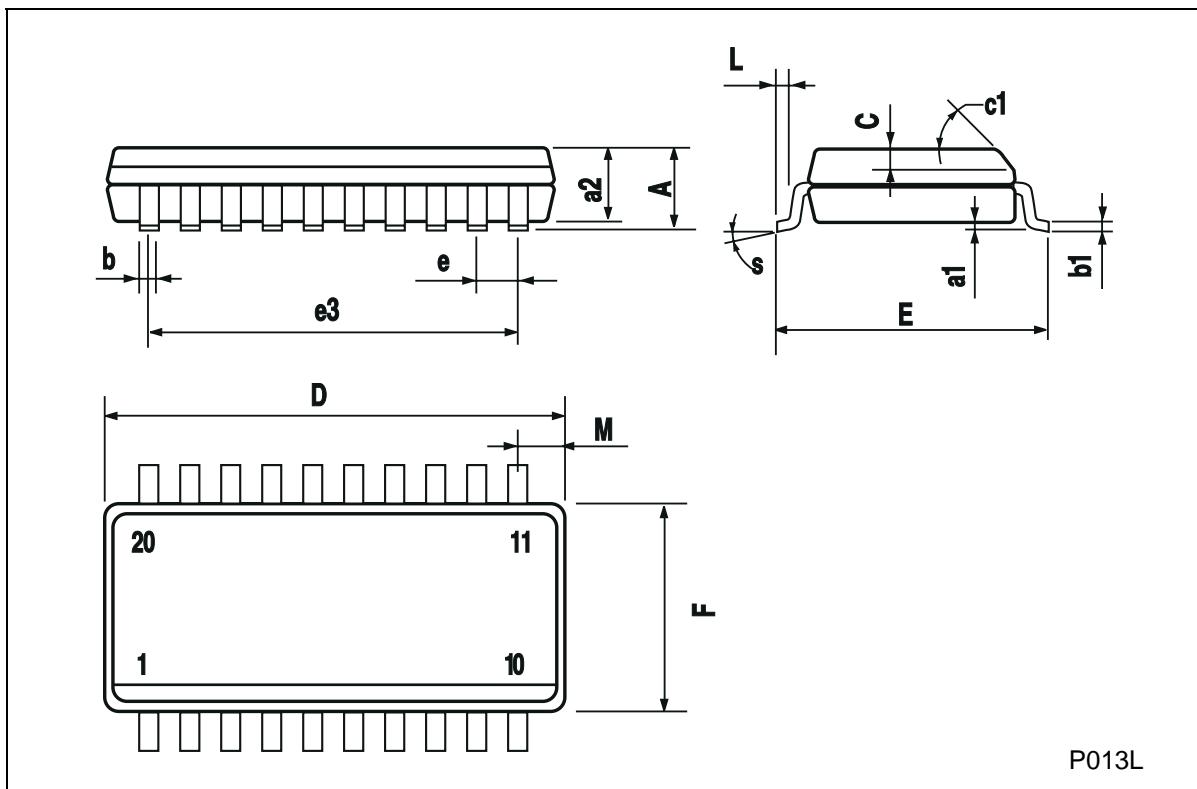
**WAVEFORM 1: PROPAGATION DELAYS (f=1MHz; 50% duty cycle)****WAVEFORM 2: OUTPUT ENABLE AND DISABLE TIME (f=1MHz; 50% duty cycle)**

Plastic DIP-20 (0.25) MECHANICAL DATA						
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.254			0.010		
B	1.39		1.65	0.055		0.065
b		0.45			0.018	
b1		0.25			0.010	
D			25.4			1.000
E		8.5			0.335	
e		2.54			0.100	
e3		22.86			0.900	
F			7.1			0.280
I			3.93			0.155
L		3.3			0.130	
Z			1.34			0.053



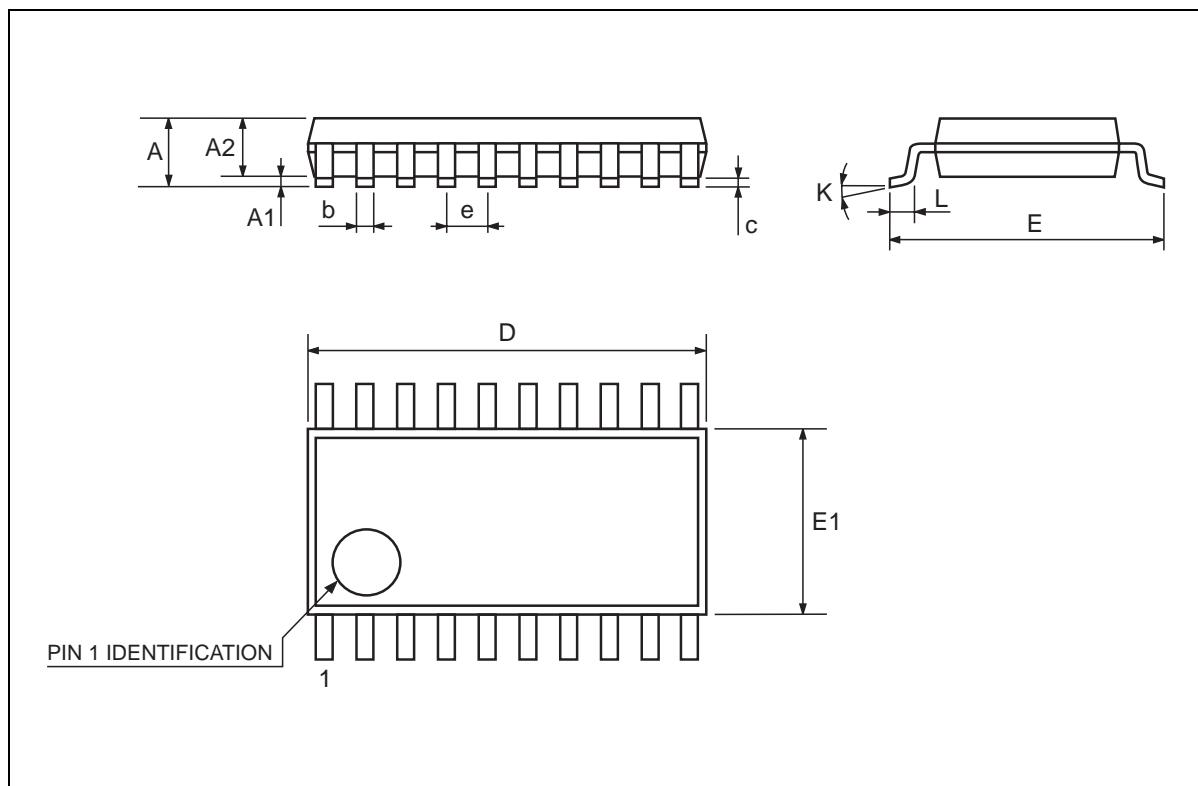
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SO-20 MECHANICAL DATA						
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			2.65			0.104
a1	0.10		0.20	0.004		0.007
a2			2.45			0.096
b	0.35		0.49	0.013		0.019
b1	0.23		0.32	0.009		0.012
C		0.50			0.020	
c1			45 (typ.)			
D	12.60		13.00	0.496		0.512
E	10.00		10.65	0.393		0.419
e		1.27			0.050	
e3		11.43			0.450	
F	7.40		7.60	0.291		0.299
L	0.50		1.27	0.19		0.050
M			0.75			0.029
S			8 (max.)			



## TSSOP20 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.1			0.433
A1	0.05	0.10	0.15	0.002	0.004	0.006
A2	0.85	0.9	0.95	0.335	0.354	0.374
b	0.19		0.30	0.0075		0.0118
c	0.09		0.2	0.0035		0.0079
D	6.4	6.5	6.6	0.252	0.256	0.260
E	6.25	6.4	6.5	0.246	0.252	0.256
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65 BSC			0.0256 BSC	
K	0°	4°	8°	0°	4°	8°
L	0.50	0.60	0.70	0.020	0.024	0.028



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